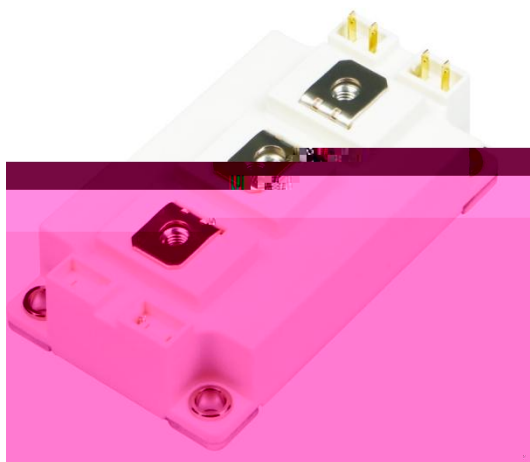
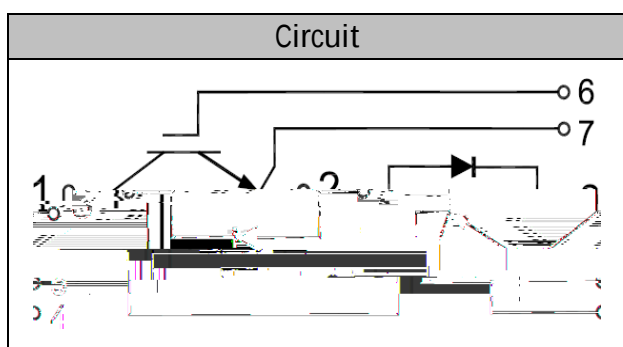




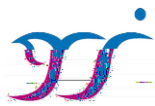
1200V
150A

Inverter for motor drive
AC and DC servo drive amplifier
UPS (Uninterruptible Power Supplies)
Soft switching welding machine



Low $V_{CE(sat)}$ with Trench technology
 $V_{ce(sat)}$ with positive temperature coefficient
High short circuit capability(10us)
Including ultra fast & soft recovery anti-parallel FWD
Low inductance
Maximum junction temperature 175

Collector-Emitter Voltage	V_{CES}	$V_{GE}=0V, I_C=1mA, T_{vj}=25$	1200	V
Continuous Collector Current	I_C	$T_c=100$	150	A
Repetitive Peak Collector Current	I_{CRM}	$t_p=1ms$	300	A
Gate-Emitter Voltage	V_{GES}	$T_{vj}=25$	20	V
Total Power Dissipation	P_{tot}	$T_c=25$ $T_{vjmax}=175$	833	W



Gate-Emitter Threshold Voltage	$V_{GE(th)}$	$V_{GE}=V_{CE}, I_C=4mA, T_{vj}=25$	5.2	5.9	6.4	V
Collector-Emitter Cut-off Current	I_{CES}	$V_{CE}=1200V, V_{GE}=0V, T_{vj}=25$			1.0	mA
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=150A, V_{GE}=15V, T_{vj}=25$		1.90	2.30	V
		$I_C=150A, V_{GE}=15V, T_{vj}=125$		2.05		
		$I_C=150A, V_{GE}=15V, T_{vj}=150$		2.20		
Gate Charge	Q_G			1.56		uC
Input Capacitance	C_{ies}	$V_{CE}=25V, V_{GE}=0V,$ $f=1MHz, T_{vj}=25$		11.0		nF
Reverse Transfer Capacitance	C_{res}			0.5		nF
Gate-Emitter leakage current	I_{GES}	$V_{CE}=0V, V_{GE}=20V, T_{vj}=25$			400	nA
Turn-on Delay Time	$t_{d(on)}$	$I_C=150A$ $V_{CE}=600V$ $V_{GE}=\pm 15V$ $R_G=4.7\Omega$ $T_{vj}=25$		196		ns
Rise Time	t_r			57		ns
Turn-off Delay Time	t					



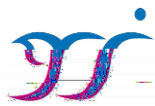
Repetitive Peak Reverse Voltage	V_{RRM}	$T_{vj}=25$	1200	V
Continuous DC Forward Current	I_F		150	A
Repetitive Peak Forward Current	I_{FRM}	$t_p=1ms$	300	A

$I_F=150A, T_{vj}=25$

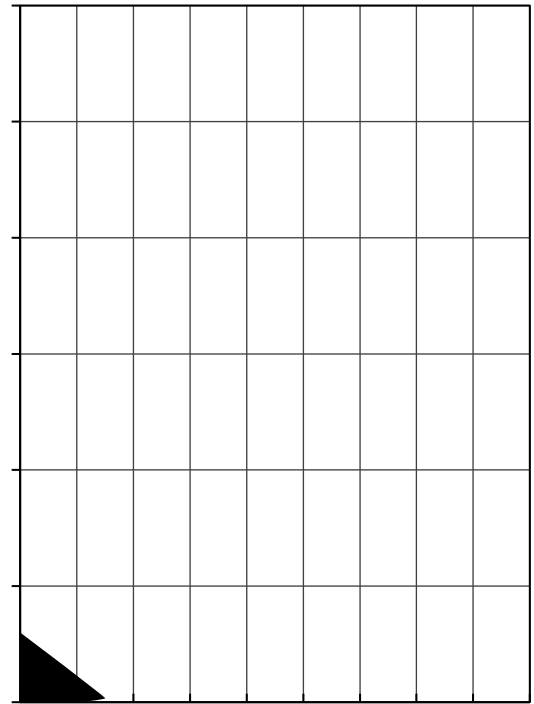
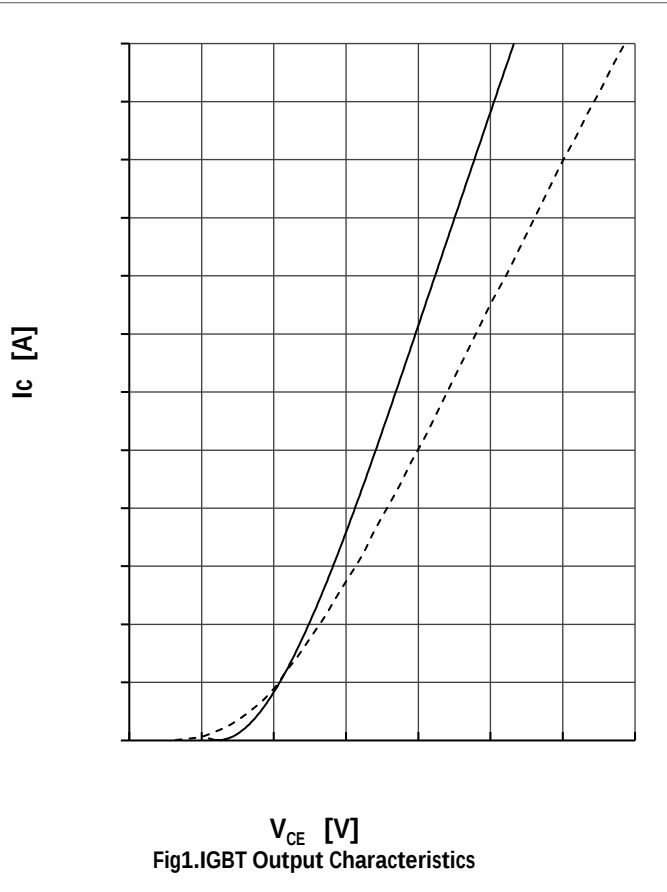
1.941 V

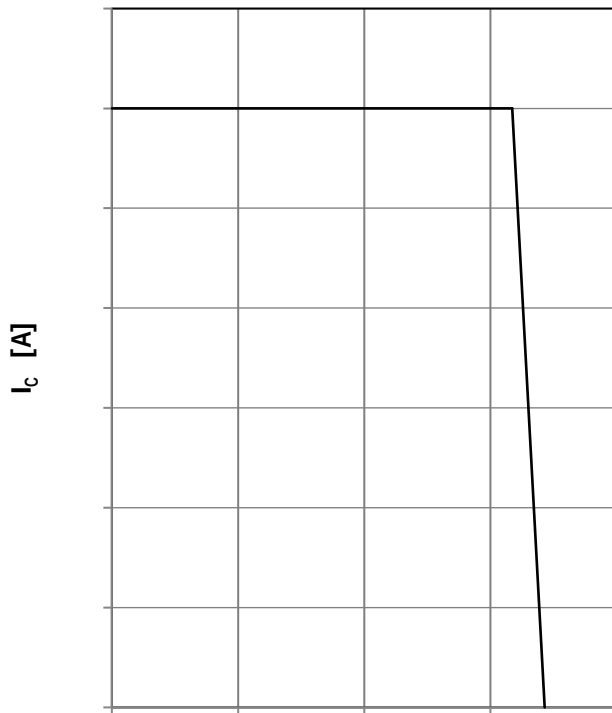
Forward Voltage

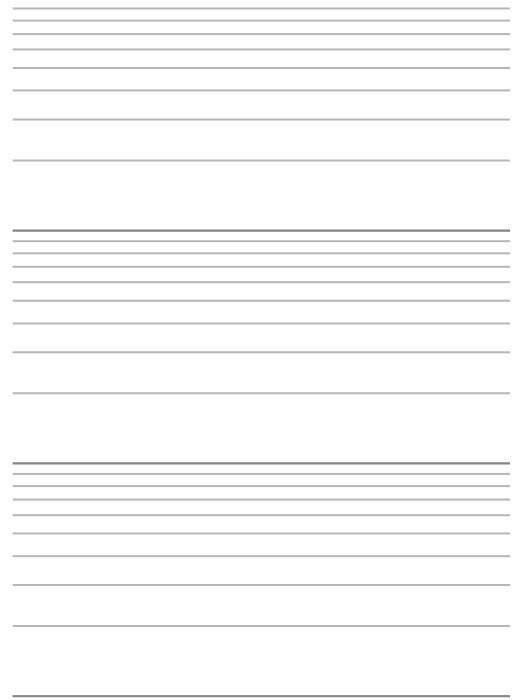
V_F

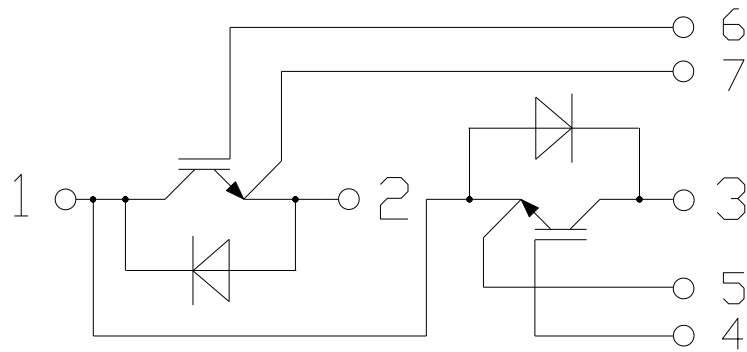


Isolation voltage	V_{isol}	$t=1min, f=50Hz$	2500			V
Maximum Junction Temperature	T_{jmax}				175	
Operating Junction Temperature	$T_{vj op}$		-40		150	
Storage Temperature	T_{stg}		-40		125	
Thermal Resistance Junction to Case	$R_{\theta JC}$	per IGBT			0.18	K/W
		per Diode			0.31	
Thermal Resistance Case to Sink	$R_{\theta CS}$	Conductive grease applied		0.012	0.035	K/W
Module Electrodes Torque	M_t	Recommended(M6)	3.0		5.0	N·m
Module to Sink Torque	M_s	Recommended(M6)	3.0		5.0	N·m
Weight of Module	G			315		g









Package Outline Information

